

GENERAL DESCRIPTION

DP2281 is a highly integrated current mode PWM control IC optimized for high performance, low standby power and cost effective offline flyback converter applications.

PWM switching frequency at normal operation is internally fixed and is trimmed to tight range. At no load or light load condition, the IC operates in extended burst mode to minimize switching loss, which can achieve less than 75mW standby.

VDD low startup current and low operating current contribute to a reliable power on startup and low standby design with DP2281.

DP2281 offers comprehensive protections coverage with automatic self-recovery feature including Cycle-by-Cycle current limiting (OCP), over load protection (OLP), on-chip Thermal Shutdown (OTP), VDD over voltage protection (VDD OVP) and VDD under voltage lockout (UVLO), etc. Excellent EMI performance is achieved with frequency shuffling and soft totem pole gate drive

The tone energy at below 20KHz is minimized in the design and audio noise is eliminated during operation.

DP2281 is offered in SOT23-6 package.

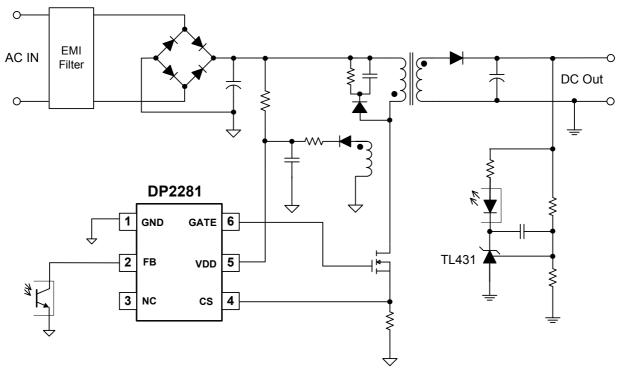
FEATURES

- Less than 75mW Standby Power at Universal Input
- Power on Soft Start Reducing MOSFET Vds Stress
- Frequency Shuffling for EMI
- Fixed 65KHz Switching Frequency
- Internal Synchronized Slope Compensation
- Low VDD Startup Current and Low Operating Current
- Built-in Leading Edge Blanking
- On-chip Thermal Shutdown
- Soft Gate Driver for Good EMI Performance
- Over Load Protection
- Cycle-by-Cycle Current Limiting
- VDD Under Voltage Lockout with Hysteresis (UVLO)
- VDD OVP & Clamp

APPLICATIONS

Offline AC/DC flyback converter for

- AC/DC Adapter
- Open-frame SMPS



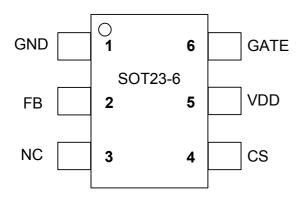
TYPICAL APPLICATION



GENERAL INFORMATION

Pin Configuration

The pin map of SOP8 package is shown as below.



Ordering Information

<u></u>				
Part Number	Description			
DP2281	SOT23-6, Pb free in T&R			

Package Dissipation Rating

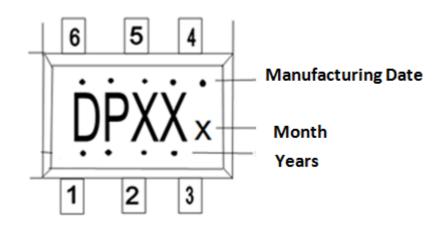
Package	R θ JA (℃/W)
SOT23-6	200

Absolute Maximum Ratings

Parameter	Value		
VDD Zener Clamp Voltage	V _{DD Clamp}		
VDD Clamp Continuous Current	10 mA		
CS Input Voltage	-0.3 to 7V		
FB Input Voltage	-0.3 to 7V		
GATE Voltage Range	20V		
Maximum Operating Junction Temperature T _J	150 °C		
Min/Max Storage Temperature T _{stq}	-55 to 150 °C		
Lead Temperature (Soldering, 10secs)	260 °C		

Note: Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute maximum-rated conditions for extended periods may affect device reliability.

Marking Information



Description:

1.1. The first line of the five points represent the assembly house commissioning date, a total of 1-31.

1.2. DPXX for product name: D represent DP brand, P represents the power supply, XX on behalf of the commodity (91: DP6291)

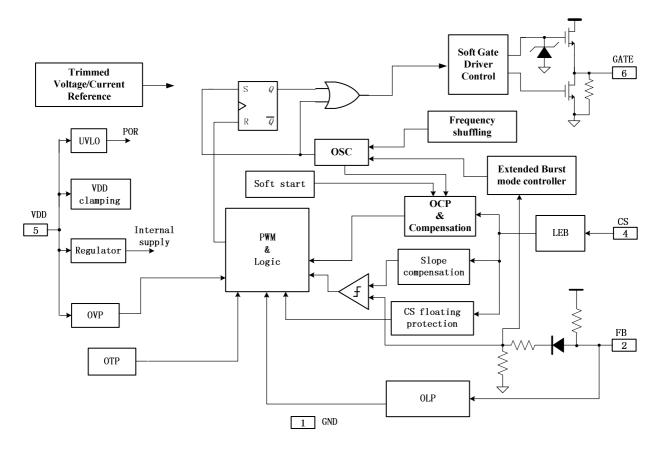
- 1.3. After the product name, X on behalf of the month, 1-12 months.
- 1.4. The third row four point on behalf of the last year.



TERMINAL ASSIGNMENTS

Pin Num	Pin Name	I/O	Description
1	GND	Р	Ground.
2	FB	I	Feedback pin. The loop regulation is achieved by connecting a photo-coupler to this pin. PWM duty cycle is determined by this pin voltage and the current sense signal at Pin 4.
3	NC	-	No connection.
4	CS	1	Current sense input.
5	VDD	Р	Power supply.
6	GATE	0	Totem-pole gate driver output to drive the external MOSFET.

BLOCK DIAGRAM





RECOMMENDED OPERATING CONDITION

Symbol	Parameter	Min	Max	Unit
VDD	VDD Supply Voltage	11	26	V
T _A	Operating Ambient Temperature	-40	85	°C

ELECTRICAL CHARACTERISTICS

 $(T_A = 25^{\circ}C, VDD=18V \text{ if not otherwise noted})$

$\begin{array}{c c c c c c c c c c c c c c c c c c c $	Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
	Supply Voltage			_	_	-	
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	I _{VDD_st}	•			2	10	uA
$\begin{array}{ c c c c c c } \hline \mbox{Index} & Standby Current & \mbox{Index} & \mbox{Index} & \mbox{VDD} & \mbox{Under} & \mbox{Voltage} & \mbox{Index} & \mbox{Index} & \mbox{VDD} & \mbox{Under} & \mbox{Voltage} & \mbox{Index} & \mbox{Index}$	VDD Op	Operation Current	V _{FB} =3V,GATE=1nF		1.2	2	mA
$ \begin{array}{c c c c c c c } V_{DD_ON} & VDD_Under_Voltage\\ Lockout Exit & & & & & & & & & & & & & & & & & & &$		Standby Current			0.4	1	mA
$\begin{array}{c c c c c c c c c c c c c c c c c c c $		- - - - - - - -		13.5	14.5	15.5	V
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	V _{DD_OFF}			8.6	9.4	10.2	V
V_{DD_Cclamp} VoltageI(V_{DD}) = 7 mA 30.5 32 33.5 32 33.5 Feedback Input Section (FB Pin) V_{FB_Open} FB Open Voltage 4.5 5.4 6 IFB_ShortFB Short Circuit CurrentShort FB Pin to GND, Measure Current 0.3 0.3 $rrA_{CS}PWM Gain\Delta V_{FB} / \Delta V_{CS}2.0NV_{skip}FB Under Voltage GATEClock is OFF1.01.0NV_{TH_OLP}Power Limiting FBThreshold Voltage3.62.0NT_{D_OLP}Power Limiting DebounceTime2.0KT_{LEB}CS Input Impedance2.0KV_{cs(max)}Current Imiting threshold0.971.01.03T_{LEB}CS Input Leading EdgeBlanking Time2.507070V_{cs(max)}Current Detectionand Control Delay606570K\Delta F(shuffle)FrequencyShufflingFrequency-444$	V _{DD OVP}	VDD OVP Threshold		27	28.5	30	V
$ \begin{array}{ c c c c c } \hline V_{FB \ Open} & FB \ Open \ Voltage & 4.5 & 5.4 & 6 \\ \hline I_{FB \ Short} & FB \ Short \ Circuit \ Current & Short \ FB \ Pin \ to \ GND, \\ Measure \ Current & 0.3 & r \\ \hline A_{CS} & PWM \ Gain & \Delta \ V_{FB} \ \Delta \ V_{CS} & 2.0 & M \\ \hline V_{skip} & FB \ Under \ Voltage \ GATE \\ Clock \ is \ OFF & 1.0 & 1.0 & 1\\ \hline V_{TH_{o}LP} & Power \ Limiting \ FB \\ Threshold \ Voltage \\ \hline T_{D_{o}OLP} & Power \ Limiting \ Debounce \\ Time & 20 & Ko \\ \hline Current \ Sense \ Input \ Section \ (CS \ Pin) \\ \hline T_{LEB} & CS \ Input \ Leading \ Edge \\ Blanking \ Time & 250 & 0.97 & 1.0 & 1.03 \\ \hline V_{cs(max)} & Current \ Imiting \ treshold & 0.97 & 1.0 & 1.03 \\ \hline T_{D_{o}CP} & Over \ Current \ Detection \\ \hline T_{D_{o}CP} & Over \ Current \ Detection \\ \hline T_{D_{o}CP} & Over \ Current \ Detection \\ \hline T_{CSC} & Normal \ Oscillation \\ \hline Fosc & Range & -4 & 4 \\ \hline \end{array}$	V_{DD_Clamp}		I(V _{DD}) = 7 mA	30.5	32	33.5	V
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	Feedback Input						
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	V _{FB} Open	FB Open Voltage		4.5	5.4	6	V
V_{skip} FB Under Voltage GATE Clock is OFF1.01.0 V_{TH_OLP} Power Limiting FB Threshold Voltage3.61.0 T_{D_OLP} Power Limiting Debounce Time4343 $Z_{FB IN}$ FB Input Impedance20KoCurrent Sense Input Section (CS Pin) T_{LEB} CS Input Leading Edge Blanking Time0.971.01.03 $V_{cs(max)}$ Current limiting threshold0.971.01.03 T_{D_OCP} Over Current Detection and Control Delay707070 $Scillator Section$ FrequencyShuffling Frequency606570Ko $\Delta F(shuffle)$ FrequencyShuffling Range-4444	I _{FB_Short}	FB Short Circuit Current			0.3		mA
V_{skip} FB Under Voltage GATE Clock is OFF1.01.0 V_{TH_OLP} Power Limiting FB Threshold Voltage3.63.6 T_{D_OLP} Power Limiting Debounce Time4343 $Z_{FB IN}$ FB Input Impedance20Kd $Z_{FB IN}$ FB Input Impedance20Kd T_{LEB} CS Input Leading Edge Blanking Time0.971.01.03 $V_{cs(max)}$ Current limiting threshold0.971.01.03 T_{D_OCP} Over Current Detection and Control Delay707070 $Fosc$ Normal Oscillation Frequency606570Kd Δ F(shuffle) / F_{osc} Frequency Shuffling Range-444	A _{CS}	PWM Gain	$\Delta V_{FB} / \Delta V_{CS}$		2.0		V/V
$\begin{array}{c c c c c c c c c c c c c c c c c c c $					1.0		V
$\begin{array}{c c c c c c c c c c c }\hline Time & & & & & & & & & & & & & & & & & & &$	V _{TH_OLP}				3.6		V
Current Sense Input Section (CS Pin) T_{LEB} CS Input Leading Edge Blanking Time250250 $V_{cs(max)}$ Current limiting threshold0.971.01.03 $T_{D_{occP}}$ Over Current Detection and Control Delay707070Oscillator Section Frequency F_{osc} Normal FrequencyOscillation Frequency606570 Δ F(shuffle)Frequency RangeShuffling Range-44	T _{D_OLP}	Time			43		ms
$\begin{tabular}{ c c c c } \hline Current Sense Input Section (CS Pin) \\ \hline T_{LEB} & CS Input Leading Edge Blanking Time & 250 & 1.0 & 1.03 \\ \hline V_{CS(max)} & Current limiting threshold & 0.97 & 1.0 & 1.03 & 1.03 \\ \hline T_{D_OCP} & Over Current Detection and Control Delay & 70 & 70 \\ \hline Over Current Detection and Control Delay & 70 & 70 & 70 \\ \hline Oscillator Section & 60 & 65 & 70 & 70 \\ \hline F_{OSC} & Requency & Shuffling & -4 & 4 \\ \hline F_{OSC} & Range & 0 & 70 & 4 \\ \hline \end{tabular}$	Z _{FB IN}				20		Kohm
I_{LEB} Blanking Time250250 $V_{cs(max)}$ Current limiting threshold0.971.01.03 $T_{D_{-}OCP}$ Over Current Detection and Control Delay7070Oscillator Section FoscNormal Oscillation Frequency606570K Δ F(shuffle) / F_{OSC} Frequency Shuffling Range-444	Current Sense I						
$\begin{tabular}{ c c c c c c c } \hline T_{D_OCP} & Over Current Detection and Control Delay & & & & & & & & & & & & & & & & & & &$	T _{LEB}	Blanking Time			250		ns
$\begin{tabular}{ c c c c c c c } \hline T_{D_OCP} & Over Current Detection and Control Delay & 70 & 70 & $$$$ $$$ $$$ $$$ $$$ $$ $$ $$ $$ $$ $$	V _{cs(max)}			0.97	1.0	1.03	V
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $					70		ns
FoscFrequency606570Frequency Δ F(shuffle)FrequencyShuffling-444 $/F_{osc}$ Range-444	Oscillator Secti						
$ \begin{array}{c c} & & & \\ $	Fosc			60	65	70	KHz
e	· · · ·	Frequency Shuffling		-4		4	%
D _{MAX} Maximum Switching Duty Cycle 66.7		Maximum Switching Duty			66.7		%
Buret Mode Base	F _{Bust}	Burst Mode Base			22		KHz
On-chip Thermal Shutdown	On-chip Therma		·				



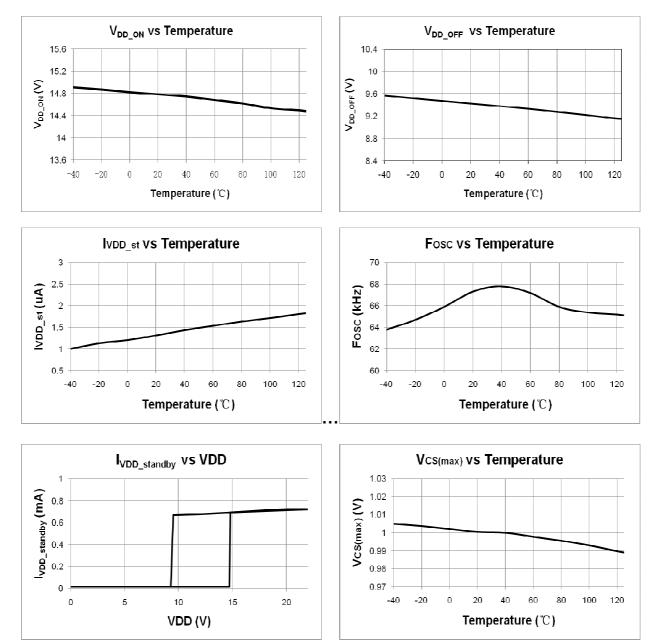


High Performance Current Mode PWM Controller

T _{SD}	Thermal Shutdown			165		°C
T _{RC}	Thermal Recovery			140		°C
GATE Driver Sect	tion (GATE pin)	· ·	•	•	•	
V _{OL}	Output Low Level	Igate_sink=20mA			1	V
V _{OH}	Output High Level	Igate_source=20mA	7.5			V
V _{G clamp}	Output Clamp Level	VDD=24V		16		V
T_r	Output Rising Time	GATE=1nF		150		ns
T_f	Output Falling Time	GATE=1nF		60		ns



CHARACTERIZATION PLOTS





OPERATION DESCRIPTION

DP2281 is a highly integrated current mode PWM control IC optimized for high performance, low standby and cost effective offline flyback converter applications. The IC can achieve less than 75mW standby power and helps the design easily to meet the international power conservation requirements.

• Startup Current and Start up Control

Startup current of DP2281 is designed to be very low so that VDD could be charged up above UVLO threshold level and device starts up quickly. A large value startup resistor can therefore be used to minimize the power loss yet reliable startup in application.

• Operating Current

The operating current of DP2281 is as low as 1.2mA. Good efficiency is achieved by the low operating current together with extended burst mode control schemes at No/light load conditions.

• Soft Start

DP2281 features an internal 4ms (typical) soft start to soften the electrical stress occurring in the power supply during startup. It is activated during the power on sequence. As soon as VDD reaches UVLO(OFF), the peak current is gradually increased from nearly zero to the maximum level of 1V. Every restart up is followed by a soft start.

• Oscillator with Frequency Shuffling

PWM switching frequency in DP2281 is fixed to 65KHz and is trimmed to tight range. To improve system EMI performance, DP2281 operates the system with 4% frequency shuffling around setting frequency.

Current Sensing and Leading Edge Blanking

Cycle-by-Cycle current limiting is offered in DP2281. The switch current is detected by a sense resistor into the CS pin. An internal leading edge blanking circuit is built in. During this blanking period (250ns, typical), the cycle-by-cycle current limiting comparator is disabled and cannot switch off the GATE driver.

• Synchronous Slope Compensation

In DP2281, the synchronous slope compensation circuit is integrated by adding voltage ramp onto the current sense input voltage for PWM generation. This greatly improves the close loop stability at CCM and prevents the sub-harmonic oscillation and thus reduces the output ripple voltage.

• Extended Burst Mode Operation

At zero load or light load condition, most of the power dissipation in a switching mode power supply is from switching loss on the MOSFET transistor, the core loss of the transformer and the loss on the snubber circuit. Reducing switching events leads to the reduction on the power loss and thus conserves the energy.

DP2281 self adjusts the switching mode according to the loading condition. At no load or light load condition, the FB input is below burst mode threshold level. Device enters Burst Mode control. The Gate drive output switches only when VDD voltage drops below a preset level and FB input is active to output an on state. Otherwise the gate drive remains at off state to minimize the switching loss thus reduce the standby power consumption to the greatest extension. The nature of high frequency switching also reduces the audio noise at any loading conditions.

• Audio Noise Free Operation

DP2281 can provide audio noise free operation from full loading to zero loading.

• On-chip Thermal Shutdown (OTP)

When the IC temperature is over 165 °C, the IC shuts down. Only when the IC temperature drops to 135 °C, IC will restart.

• VDD OVP and Zener Clamp

When VDD voltage is higher than 28.5V (typical), the IC will stop switching. This will cause VDD fall down to be lower than VDD_OFF (typical 9.4V) and then the system will restart up again. An internal 32V (typical) zener clamp is integrated to prevent the IC from damage.

• Soft Gate Drive

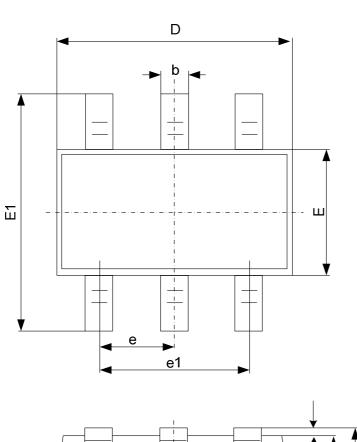
DP2281 has a soft totem-pole gate driver with optimized EMI performance. An internal 16V clamp is added for MOSFET gate protection at higher than expected VDD input. Too weak the gate drive strength results in higher conduction and switch loss of MOSFET while too strong gate drive output compromises the EMI.

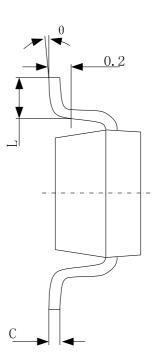
Good tradeoff is achieved through the built-in totem pole gate drive design with right output strength and dead time control. The low idle loss and good EMI system design is easier to achieve with this dedicated control scheme.

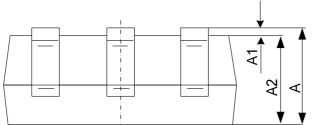


SOT23-6

Package Dimension







Symbol	Dimensions I	n Millimeters	Dimension	s In Inches
Symbol	Min	Max	Min	Max
A	0.900	1.200	0.035	0.047
A1	0.000	0.150	0.000	0.006
A2	0.900	1.100	0.035	0.043
b	0.300	0.500	0.012	0.020
С	0.100	0.200	0.004	0.008
D	2.800	3.020	0.110	0.119
E	1.500	1.700	0.059	0.067
E1	2.600	3.000	0.102	0.118
е	0.950 (BSC)		0.037	(BSC)
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°